

Cleveland State University
EngagedScholarship@CSU



Physics Faculty Publications

Physics Department

8-9-2013

Writing and Deleting Single Magnetic Skyrmions

Niklas Romming
University of Hamburg

Christian Hanneken

Matthias Menzel

Jessica E. Bickel
Cleveland State University, j.e.bickel@csuohio.edu

Boris Wolter

See next page for additional authors

Follow this and additional works at: https://engagedscholarship.csuohio.edu/sciphysics_facpub

 Part of the [Physics Commons](#)

How does access to this work benefit you? Let us know!

Publisher's Statement

This is the author's version of the work. It is posted here by permission of the AAAS for personal use, not for redistribution. The definitive version was published in *Science* on 341 and August 9, 2013, DOI: 10.1126/science.1240573

Repository Citation

Romming, Niklas; Hanneken, Christian; Menzel, Matthias; Bickel, Jessica E.; Wolter, Boris; von Bergmann, Kirsten; Kubetzka, André; and Wiesendanger, Roland, "Writing and Deleting Single Magnetic Skyrmions" (2013). *Physics Faculty Publications*. 198.
https://engagedscholarship.csuohio.edu/sciphysics_facpub/198

This Article is brought to you for free and open access by the Physics Department at EngagedScholarship@CSU. It has been accepted for inclusion in Physics Faculty Publications by an authorized administrator of EngagedScholarship@CSU. For more information, please contact library.es@csuohio.edu.

Authors

Niklas Romming, Christian Hanneken, Matthias Menzel, Jessica E. Bickel, Boris Wolter, Kirsten von Bergmann, André Kubetzka, and Roland Wiesendanger

Writing and Deleting Single Magnetic Skyrmions

Niklas Romming, Christian Hanneken, Matthias Menzel, Jessica E. Bickel, Boris Wolter, Kirsten von Bergmann, André Kubetzka, Roland Wiesendanger

Topologically nontrivial spin textures have recently been investigated for spintronic applications. Here, we report on an ultrathin magnetic film in which individual skyrmions can be written and deleted in a controlled fashion with local spin-polarized currents from a scanning tunneling microscope. An external magnetic field is used to tune the energy landscape, and the temperature is adjusted to prevent thermally activated switching between topologically distinct states. Switching rate and direction can then be controlled by the parameters used for current injection. The creation and annihilation of individual magnetic skyrmions demonstrates the potential for topological charge in future information-storage concepts.

Magnetic skyrmions (I) are topologically stable, particle like spin configurations that carry a characteristic topological charge S , which is essentially a measure of the magnetization curvature. For a surface area A ,

S is defined as $S = \frac{1}{4\pi} \int_A \mathbf{n} \cdot \left(\frac{\partial \mathbf{n}}{\partial x} \times \frac{\partial \mathbf{n}}{\partial y} \right) dx dy$, where

\mathbf{n} is the normalized magnetization vector and x and y are the spatial coordinates. A single

skyrmion carries a quantized charge of $S = +1$; for an antiskyrmion, the charge is $S = -1$. In contrast, a spin spiral and the ferromagnetic (FM)

state are topologically trivial with $S = 0$. Transitions between such topologically distinct states are forbidden within a continuous description of \mathbf{n} , but in a real system with magnetic moments on an atomic lattice, strict topological protection does not exist. Instead, the states are separated by a finite energy barrier. Magnetic skyrmions typically arrange in two dimensional (2D) lattices (2–4). An important prerequisite for their formation is broken inversion symmetry, which is fulfilled not only for samples with chiral crystal structure (4–9), but also for magnetic film systems, in which the top and bottom interfaces are different (10–12). In recent years, magnetic skyrmions have been observed in a number of systems with broken crystal inversion symmetry ranging from metallic and semiconducting (4–7) to insulating (8, 9). Each of these systems displays a spin spiral phase in zero field (Fig. 1A), resulting from a competition of magnetic exchange and Dzyaloshinskii-Moriya interaction, and can be driven into a hexagonal skyrmion lattice phase (Fig. 1B) by the application of an external magnetic field B . In contrast to the spin spiral state, which is magnetically compensated, the hexagonal skyrmion lattice exhibits a net magnetization and is, therefore, favored by the Zeeman energy. By further increasing the magnetic field, the parallel alignment of the magnetic moments becomes energetically more and more favorable, until the skyrmion phase is eventually saturated to the FM phase (Fig. 1C) (5). Both of these phase transitions are accompanied by a change of topological charge. In thin films, the skyrmion lattice

phase space increases as the thickness of the sample is decreased (7). In such 2D systems, the diameter of the skyrmions can exceed the film thickness (5, 7), which may be favorable for controlled skyrmion manipulation by surface techniques. At the ultimate limit, a single atomic layer of Fe on Ir(111) exhibits a skyrmion lattice, even in the absence of an external field. This skyrmion lattice has square symmetry and a period of only 1 nm (12); however, driving it into a different topological state has been challenging.

The manipulation of skyrmion lattices may require substantially smaller current densities compared with the manipulation of domain walls in conventional ferromagnetic systems, which makes skyrmions a promising candidate for spintronic applications (13–18). However, even though single skyrmions were observed experimentally (5), and the creation of skyrmions by radial currents was studied theoretically (19), the manipulation or creation of individual skyrmions has presented difficulties. To design an ultrathin film system exhibiting skyrmions that can be manipulated with a local probe, we cover the Fe layer on Ir(111) with an additional atomic layer of Pd (20). We thereby modify the top interface and, thus, the magnetic interactions within the film. As Pd is known to be easily polarized by adjacent magnetic moments (21), we expect the resulting PdFe bilayer to behave as a single magnetic entity.

Figure 1 shows the magnetic field dependence of the PdFe bilayer on Ir(111) at a temperature T of 8 K. In zero field (Fig. 1D), the spin polarized

scanning tunneling microscopy (SP-STM) image (20) reveals a spin spiral ground state with a period of 6 to 7 nm. When the magnetic field is increased to $B = +1$ T (Fig. 1E), skyrmions can be observed coexisting with remaining areas of spiral ordering. Even higher values of B lead to a pure hexagonal skyrmion lattice (Fig. 1F) and, eventually, to saturation of the film to a FM phase (Fig. 1G); here only a few single skyrmions, pinned at atomic defects, remain at $B = +2$ T. This field dependent behavior is similar to previously studied systems (5), and the transitions are reversible at $T = 8$ K: Removing the field leads to qualitatively the same magnetic structure as in Fig. 1D, with small variations in the details of the spiral position and direction.

Figure 2A depicts a comparable sample at $B = +1$ T, this time measured at $T = 4.2$ K. Whereas the trend of skyrmion formation at the cost of the spiral phase is similar, fewer skyrmions are observed compared with the measurement at $T = 8$ K (see Fig. 1E). This may be partly due to a small shift with temperature of the critical magnetic field needed for the phase transition (4, 5, 7) or to small differences in the local environment. However, the main reason is reduced thermal energy, which prevents the system from reaching energetically lower states. A change of B at $T = 4.2$ K may not necessarily lead to the lowest energy state; instead, a metastable state may be preserved. We demonstrated a transition from a metastable to a lower energy state by depositing energy into the system by tunneling with higher energy electrons: After scanning the surface area at an increased bias voltage of $U = +1$ V, the spin spiral has locally transformed into skyrmions (Fig. 2B). A higher degree of control can be achieved by injecting higher energy electrons locally, as in Fig. 2, C and D, where skyrmions are imprinted into the ferromagnetic phase; by voltage sweeps with the STM tip held stationary, skyrmions can be created one by one below the tip or in close vicinity (Fig. 2E). Apparently, atomic defects act as preferred nucleation and pinning sites (see also fig. S2). In such a writing process, a topological charge S is created. The field dependent potential can be sketched as in Fig. 2F, where B_0 is the field at which the two states are energetically degenerate. For $B < B_0$, the energetically lower state is the skyrmion ($S = 1$); for $B > B_0$, it is the FM state ($S = 0$). When we start from the FM state and lower the external field to $B < B_0$ (as in Fig. 2C), the system can be transferred to the skyrmion state only if the remaining energy barrier is overcome, either by thermal fluctuations or if energy is supplied by other means (e.g., by the tunneling electrons).

For magnetic field values close to B_0 , skyrmions can be created and annihilated reversibly. In this way, topological charge can be used to store information, as demonstrated in Fig. 3: By locally injecting electrons, we can generate any desired skyrmion configuration for the four pinning sites within the area. In the series of

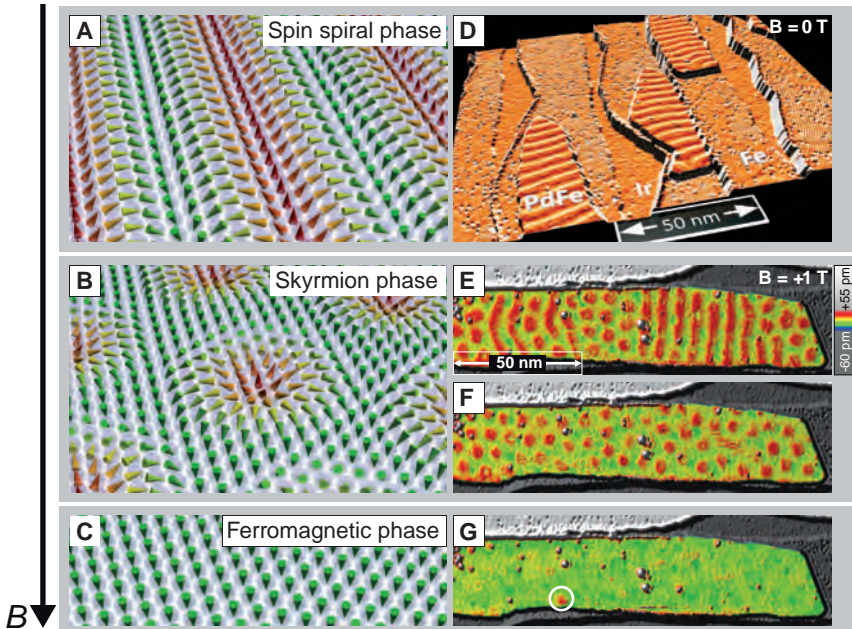


Fig. 1. Magnetic field dependence of the PdFe bilayer on the Ir(111) surface at $T = 8$ K. (A to C) Perspective sketches of the magnetic phases. (D) Overview SP-STM image, perspective view of constant-current image colored with its derivative. (E to G) PdFe bilayer at different magnetic fields ($U = +50$ mV, $I = 0.2$ nA, magnetically out-of-plane sensitive tip). (E) Coexistence of spin spiral and skyrmion phase. (F) Pure skyrmion phase. (G) Ferromagnetic phase. A remaining skyrmion is marked by the white circle.

difference SP STM images in Fig. 3, B to E, the skyrmions are annihilated one by one until no skyrmion is present (in Fig. 3F); skyrmions are

then created in a different sequence until the starting configuration is reached again (Fig. 3, G to J). The writing and deleting was done between the

images by local voltage sweeps. This series demonstrates that the skyrmions can be addressed individually and independently, even in close proximity to one another.

Whereas controlled skyrmion creation and annihilation is demonstrated, the intermediate magnetization states during the switching process cannot be imaged directly because of the limited time resolution in our experiment. We consider the following mechanisms that may contribute to switching (22, 23): (i) thermal noise, (ii) a local temperature increase caused by the injected power (Joule heating), (iii) nonthermal excitations from the injected electrons, and (iv) spin transfer torque (STT). The latter depends on the spin polarization of the tunnel current and its direction. To discriminate between these different contributions, we performed measurements as a function of bias voltage U , tunnel current I , and applied magnetic field B (23, 24): With the tip held stationary above atomic pinning sites, we recorded the time evolution of the system (20). The observed magnetic telegraph noise (see insets in Fig. 4) occurs because of repetitive switching between a skyrmion ($S = 1$) and the FM state ($S = 0$). From each measurement, typically consisting of 1000 switching events, the switching rate f and the probability to observe a skyrmion P can be extracted (22). We find that the switching process is very sensitive to the energy of the tunneling electrons eU (where e is the elementary charge) (Fig. 4A): At $U = 300$ mV, switching occurs, on average, once every 15 s at $I = 300$ nA. Toward lower bias voltages, switching becomes increasingly rare, which facilitates nonperturbing imaging. For higher voltages, the rate increases rapidly, allowing efficient skyrmion manipulation. In contrast, the current dependence at fixed bias voltage (Fig. 4B) is much weaker. The switching rate depends linearly on I within the investigated current

Fig. 2. Manipulation of the magnetic states of the PdFe bilayer at $T = 4.2$ K.

(A and B) SP-STM images at $B = +1$ T ($U = +100$ mV, $I = 0.5$ nA, magnetically in-plane sensitive tip). Whereas (A) shows the sample in its initial magnetic state after sweeping the field up from $B = 0$ T to $+1$ T, in (B) the spin spiral has locally transformed into skyrmions after supplying energy by a higher-voltage STM scan with $U = +1$ V, $I = 0.5$ nA. (C) SP-STM image of the initial state at $B = +1.8$ T after sweeping the magnetic field down from $+3$ T. Four skyrmions are marked by circles ($U = +100$ mV, $I = 1$ nA, magnetically out-of-plane sensitive tip). (D) Successive population of the island with skyrmions by injecting higher-energy electrons through local voltage sweeps (20) (fig. S2). (E) Concept of skyrmion manipulation with local currents from an STM tip. (F) Sketch of the field-dependent potential for a skyrmion (Sk; $S = 1$) and the FM state ($S = 0$). B_0 is the field where the two states are energetically degenerate.

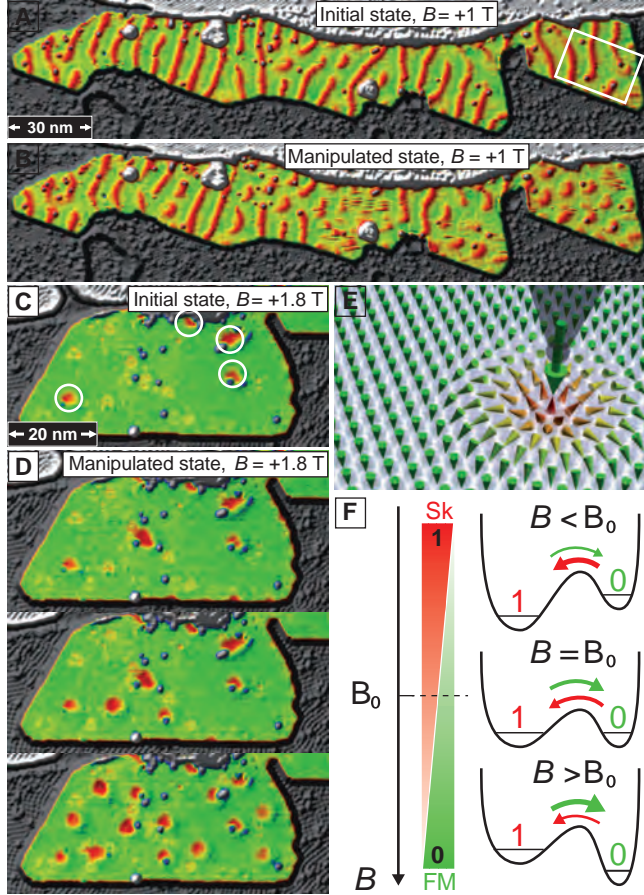
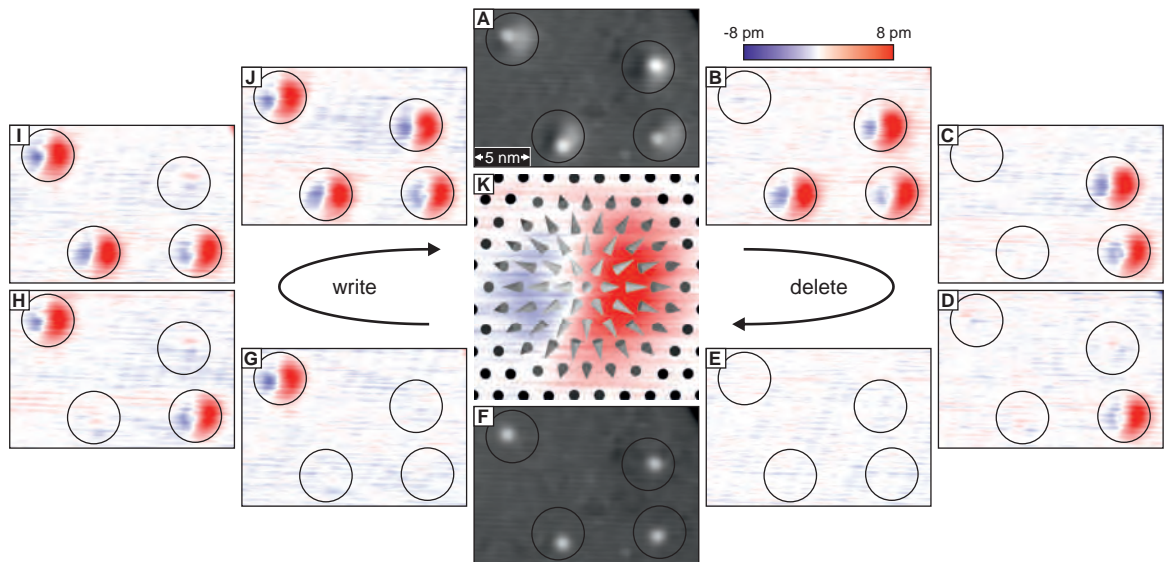


Fig. 3. Creation and annihilation of single skyrmions.

(A) Constant-current image of a sample region with four defects (see box in Fig. 2A), each hosting a skyrmion marked by a circle containing ~ 270 surface atoms ($U = +250$ mV, $I = 1$ nA, $B = +3.25$ T, $T = 4.2$ K, magnetically in-plane sensitive tip). (B to E) Sequence of difference SP-STM images [with respect to (F)] showing the selective erasing of all four skyrmions using local voltage sweeps (feedback loop switched off while bias voltage was increased to $+750$ mV). (F) The sample area without skyrmions (constant-current image) and (G to J) their successive rewriting (difference images). (K) Schematic spin configuration with distances twice the atomic lattice, superimposed on the experimental data: The asymmetric appearance of the skyrmions results from a canted SP-STM tip magnetization in this experiment.



(K) Schematic spin configuration with distances twice the atomic lattice, superimposed on the experimental data: The asymmetric appearance of the skyrmions results from a canted SP-STM tip magnetization in this experiment.

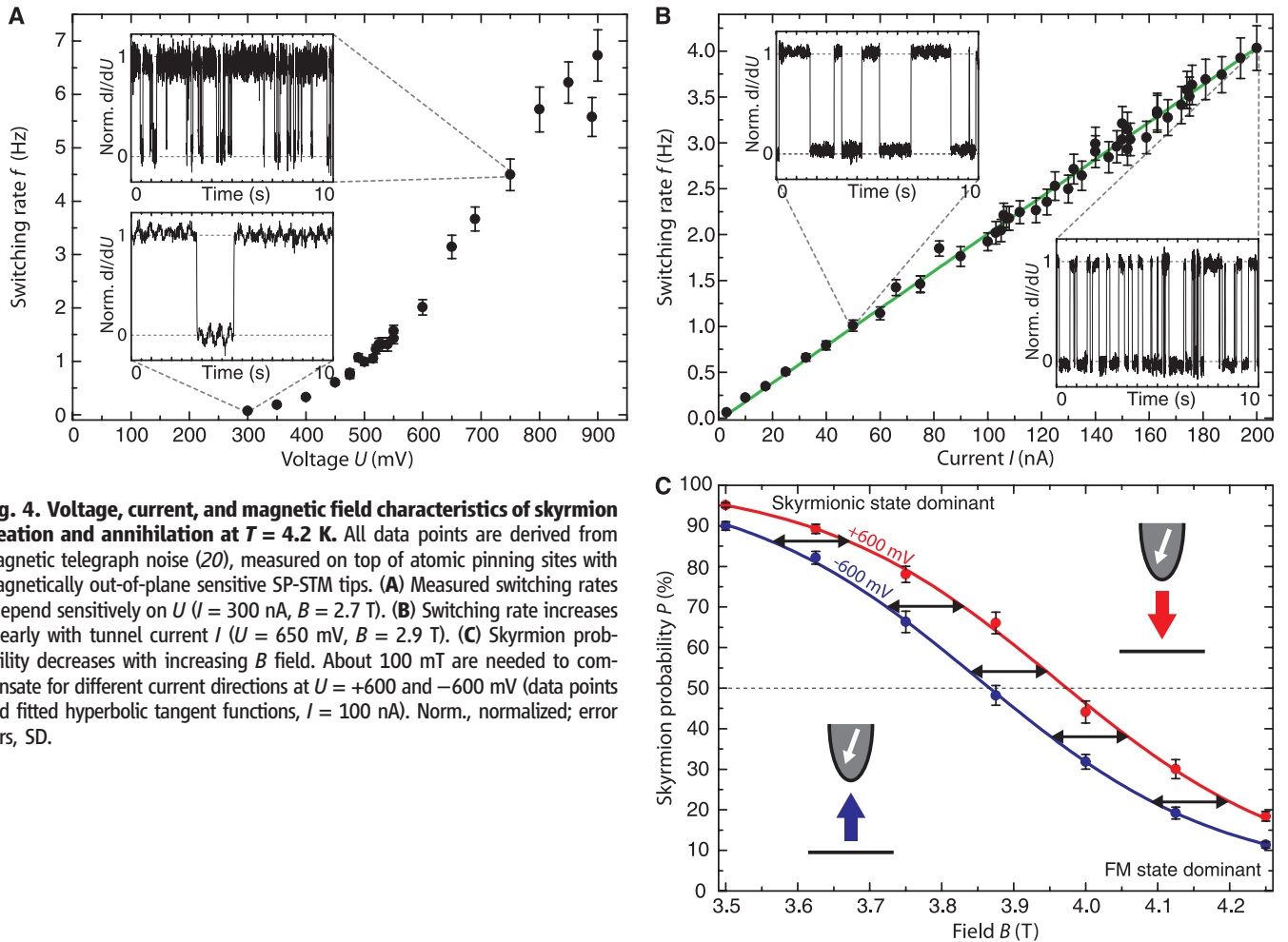


Fig. 4. Voltage, current, and magnetic field characteristics of skyrmion creation and annihilation at $T = 4.2$ K. All data points are derived from magnetic telegraph noise (20), measured on top of atomic pinning sites with magnetically out-of-plane sensitive SP-STM tips. **(A)** Measured switching rates f depend sensitively on U ($I = 300$ nA, $B = 2.7$ T). **(B)** Switching rate increases linearly with tunnel current I ($U = 650$ mV, $B = 2.9$ T). **(C)** Skyrmion probability decreases with increasing B field. About 100 mT are needed to compensate for different current directions at $U = +600$ and -600 mV (data points and fitted hyperbolic tangent functions, $I = 100$ nA). Norm., normalized; error bars, SD.

range, which means that, on average, the number of electrons needed for switching, $I/(fe)$, is constant, independent of I . We found that, in the limit of low bias and low current, the switching rate approaches zero, which shows that thermally activated switching (i) does not play a role at $T = 4.2$ K. The injected power IU is also not a decisive quantity for the switching process. At constant power, the switching rates still depend critically on U . Thus, local thermal heating (ii) can be ruled out as a driving mechanism. Instead, the energy of the injected electrons $|eU|$ (iii) appears to be the dominant factor determining the switching rate. Figure 4C shows the magnetic field dependent skyrmion probability P for the two current directions, while $|eU|$ and $|I|$ are fixed. As expected, P decreases with increasing B (Fig. 2F). More importantly, the data points show a uniform shift of $\Delta B \approx 100$ mT upon current reversal. Because all other parameters are fixed, this indicates that ΔB results from a difference of the STT (iv) at the chosen bias voltages (23). Along with the external field B , the STT is, thus, a means to control the directionality of the switching. Whereas the switching trajectory within the energy landscape and the coupling of the spin polarized tunnel current to the magnetic states re-

main to be identified for the optimization of the switching process, our work demonstrates the feasibility of using spin polarized tunnel currents for the controlled manipulation of individual skyrmions.

References and Notes

1. T. H. R. Skyrme, *Nucl. Phys.* **31**, 556–569 (1962).
2. A. Bogdanov, A. Hubert, *J. Magn. Magn. Mater.* **138**, 255–269 (1994).
3. U. K. Röfßler, A. N. Bogdanov, C. Pfleiderer, *Nature* **442**, 797–801 (2006).
4. S. Mühlbauer *et al.*, *Science* **323**, 915–919 (2009).
5. X. Z. Yu *et al.*, *Nature* **465**, 901–904 (2010).
6. W. Münzer *et al.*, *Phys. Rev. B* **81**, 041203 (2010).
7. X. Z. Yu *et al.*, *Nat. Mater.* **10**, 106–109 (2011).
8. T. Adams *et al.*, *Phys. Rev. Lett.* **108**, 237204 (2012).
9. S. Seki, X. Z. Yu, S. Ishiwata, Y. Tokura, *Science* **336**, 198–201 (2012).
10. M. Bode *et al.*, *Nature* **447**, 190–193 (2007).
11. P. Ferriani *et al.*, *Phys. Rev. Lett.* **101**, 027201 (2008).
12. S. Heinze *et al.*, *Nat. Phys.* **7**, 713–718 (2011).
13. F. Jonietz *et al.*, *Science* **330**, 1648–1651 (2010).
14. N. S. Kiselev, A. N. Bogdanov, R. Schäfer, U. K. Röfßler, *J. Phys. D Appl. Phys.* **44**, 392001 (2011).
15. J. Zang, M. Mostovoy, J. H. Han, N. Nagaosa, *Phys. Rev. Lett.* **107**, 136804 (2011).
16. T. Schulz *et al.*, *Nat. Phys.* **8**, 301–304 (2012).
17. X. Z. Yu *et al.*, *Nat. Commun.* **3**, 988 (2012).
18. A. Fert, V. Cros, J. Sampaio, *Nat. Nanotechnol.* **8**, 152–156 (2013).
19. Y. Tchoe, J. H. Han, *Phys. Rev. B* **85**, 174416 (2012).
20. Materials and methods are available as supplementary materials on Science Online.
21. W. Weber, D. A. Wesner, G. Güntherodt, U. Linke, *Phys. Rev. Lett.* **66**, 942–945 (1991).
22. S. Krause, L. Berbil Bautista, G. Herzog, M. Bode, R. Wiesendanger, *Science* **317**, 1537–1540 (2007).
23. A. A. Khajetoorians *et al.*, *Science* **339**, 55–59 (2013).
24. S. Loth, S. Baumann, C. P. Lutz, D. M. Eigler, A. J. Heinrich, *Science* **335**, 196–199 (2012).

Acknowledgments: We thank S. Krause, A. A. Khajetoorians, A. Sonntag, S. Heinze, B. Dupé, and Ch. Hübner for discussions. We acknowledge financial support from the Deutsche Forschungsgemeinschaft via grants SFB668 and GrK 1286, the European Union via the European Research Council Advanced Grant FURORE, and the Hamburg Cluster of Excellence NANOSPINTRONICS.